



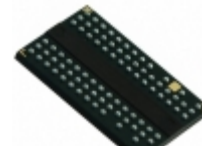
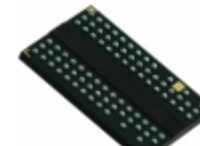




 Long-term Support World Class Quality	<h2 style="color: #E67E22;">IS43DR16640B-3DBI</h2>	
	Hersteller-Teilenummer:	IS43DR16640B-3DBI
	Hersteller / Marke:	ISSI (Integrated Silicon Solution, Inc.)
	Teil der Beschreibung:	IC SDRAM 1GBIT 333MHZ 84BGA
	Datenblätter:	 IS43DR16640B-3DBI.pdf
	RoHs Status:	Enthält Blei / RoHS nicht konform
Lagerzustand:	New original, 854 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	IS43DR16640B-3DBI
Hersteller	ISSI (Integrated Silicon Solution, Inc.)
Beschreibung	IC SDRAM 1GBIT 333MHZ 84BGA
Kategorie	Integrierte Schaltungen (ICs) > Erinnerung
Teilstatus	854 pcs Stock
Serie	-
Betriebstemperatur	-40°C ~ 85°C (TA)
Schnittstelle	Parallel
Verpackung / Gehäuse	84-TFBGA
Supplier Device-Gehäuse	84-TWBGA (8x12.5)
Spannungsversorgung	1.7 V ~ 1.9 V
Speichertyp	Volatile
Geschwindigkeit	333MHz
Speichergröße	1Gb (64M x 16)
Speicherformat	DRAM
Verpackung	Tray

IS43DR16640B-3DBI ist neu im Original, Suche IS43DR16640B-3DBI Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IS43DR16640B-3DBI ISSI (Integrated Silicon Solution, Inc.) mit Garantie und Vertrauen. Anfrage IS43DR16640B-3DBI: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IS43DR16640B-3DBI-TR ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 1GBIT 333MHZ 84BGA</p>	 <p>IS43DR16640B-3DBL ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 1GBIT 333MHZ 84BGA</p>	 <p>IS43DR16640B-3DBL-TR ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 1GBIT 333MHZ 84BGA</p>	 <p>IS43DR16640B-3DBLI-TR ISSI (Integrated Silicon Solution, Inc.) IC SDRAM 1GBIT 333MHZ 84BGA</p>
 <p>IS43DR16640B-25EBL ISSI (Integrated Silicon Solution, Inc.) IC DRAM 1G PARALLEL 84TWBGA</p>	 <p>IS43DR16640B-25EBLI ISSI (Integrated Silicon Solution, Inc.) IC DRAM 1G PARALLEL 84TWBGA</p>	 <p>IS43DR16640B-25EBLI-TR ISSI (Integrated Silicon Solution, Inc.) IC DRAM 1G PARALLEL 84TWBGA</p>	 <p>IS43DR16640B-25EBL-TR ISSI (Integrated Silicon Solution, Inc.) IC DRAM 1G PARALLEL 84TWBGA</p>

heiße Teile

Mehr

IS42VM16400K-75BLI	IS42VM32200E-7BL-BM	IS42VM32200E-7TL-BM	IS42VM32400E-75TLI-TR	IS42VS16100C1-10TL
IS42VS16100E-10BL	IS42VS16100E-10TL	IS42VS16100E-10TLI	IS42VS16100E-75TL	IS43DR16128-3DBLI
IS43DR16320B-25DBL	IS43DR16320B-25DBLI	IS43DR16320B-25EBL	IS43DR16320B-25EBLI	IS43DR16320B-37CBL
IS43DR16320B-3DBI	IS43DR16320B-3DBL	IS43DR16320B-3DBLI	IS43DR16320B25DBLI	IS43DR16320C-25DBLI-TR
IS43DR16640A-3DBI	IS43DR16640A-3DBL	IS43DR16640A-3DBLI	IS43DR16640B-25DBLI	IS43DR16640B-25DBLI-TR
IS43DR16640B-3DBL	IS43DR16640C-25DBLI-TR	IS43DR81280A-25DBLI	IS43DR81280A-3DBL	IS43DR81280A-3DBLI
IS43DR82560B-25EBLI	IS43DR82560B-25EBLI	IS43DR86400B-3DBL	IS43LR32160B-6BL	IS43R16160B-5TLI
IS43R16160B-6BI	IS43R16160B-6TL	IS43R16160D-5BL	IS43R16160D-5TL-TR	IS43R16160D-6BI
IS43R16320B-6TL	IS43R16320D-5TLI	IS43R16320D-6BI	IS43R16320D-6BI	IS43R16320D-6BI-TR
IS43R16320D-6BI-TR	IS43R16800CC-6TL	IS43R16800E-5TL	IS43R32800B-5BI	IS43R32800B-5BL

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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